Silicon PNP Epitaxial

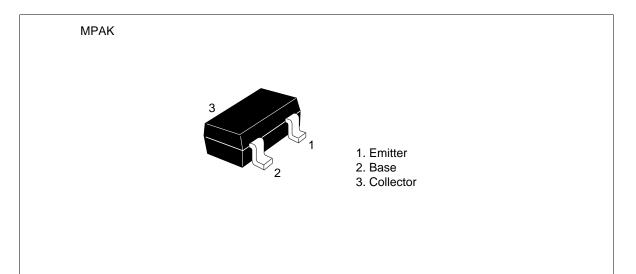
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ADE-208-1010 (Z) 1st. Edition Mar. 2001

Application

Low frequency small signal amplifier

Outline





Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	-90	V
Collector to emitter voltage	V _{CEO}	-90	V
Emitter to base voltage	V _{EBO}	-5	V
Collector current	Ι _c	-50	mA
Collector power dissipation	Pc	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	-90	_	_	V	$I_c = -1$ mA, $R_{BE} = \infty$
Collector cutoff current	I _{CBO}	—	—	-0.5	μΑ	$V_{CB} = -75 \text{ V}, I_{E} = 0$
DC current transfer ratio	$h_{\rm FE}^{*1}$	250	—	800		$V_{ce} = -12 \text{ V}, \text{ I}_{c} = -2 \text{ mA}$
Base to emitter voltage	V_{BE}	—	—	-0.75	V	$V_{ce} = -12 \text{ V}, \text{ I}_{c} = -2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	—	-0.5	V	$I_{c} = -10 \text{ mA}, I_{B} = -1 \text{ mA}$
Gain bandwidth product	f _⊤	_	200	_	MHz	$V_{ce} = -12 \text{ V}, \text{ I}_{c} = -2 \text{ mA}$
Collector output capacitance	Cob	—	1.6	—	pF	$V_{_{CB}} = -25 \text{ V}, \text{ I}_{_{E}} = 0, \text{ f} = 1 \text{ MHz}$
Note: 1. The 2SA1171 is gro	puped by h	_{FE} as follo	ows.			
Grade D E						
Mark PD PI	=	-				

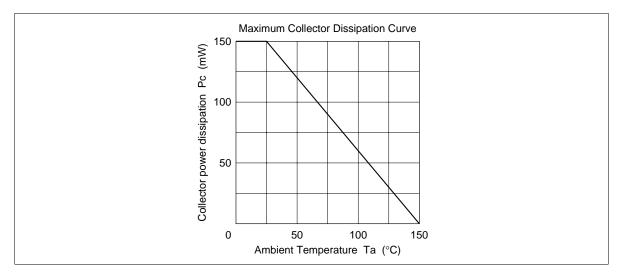
See characteristic curves of 2SA872.

250 to 500

400 to 800

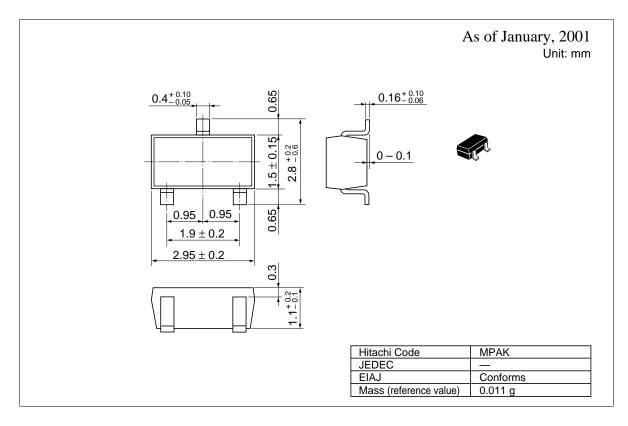
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 $\mathbf{h}_{\rm FE}$



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Package Dimensions



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